

RELIABILITY REPORT FOR MAX3093EEUE+ PLASTIC ENCAPSULATED DEVICES

January 24, 2011

MAXIM INTEGRATED PRODUCTS

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Approved by
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Conclusion

The MAX3093EEUE+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX3093E/MAX3094E are rugged, low-power, quad, RS-422/RS-485 receivers featuring electrostatic discharge (ESD) protection for use in harsh environments. All receiver inputs are protected to ±15kV using IEC 1000-4-2 Air-Gap Discharge, ±8kV using IEC 1000-4-2 Contact Discharge, and ±15kV using the Human Body Model. The MAX3093E operates from a +5V supply, while the MAX3094E operates from a +3.3V supply. Receiver propagation delays are guaranteed to within ±8ns of a predetermined value, thereby ensuring device-to-device matching across production lots. The devices feature a 1nA low-power shutdown mode in which the receiver outputs are high impedance. When active, these receivers have a fail-safe feature that guarantees a logic-high output if the input is open circuit. They also have a quarter-unit-load input impedance that allows 128 receivers on a bus. The MAX3093E/MAX3094E are pin-compatible, low-power upgrades to the industry-standard '34C86. They are available in space-saving TSSOP, narrow SO, and PDIP packages.



II. Manufacturing Information

A. Description/Function:	$\pm 15 kV$ ESD-Protected, 10Mbps, 3V/5V, Low-Power Quad RS-422/RS-485 Receivers
B. Process:	B3

Malaysia, Philippines, Thailand

Oregon

July 22, 2000

- C. Number of Device Transistors:
- D. F abrication Location:
- E. Assembly Location:
- F. Date of Initial Production:

III. Packaging Information

A. Package Type:	16-pin TSSOP
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-2601-0031
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	106°C/W
K. Single Layer Theta Jc:	27°C/W
L. Multi Layer Theta Ja:	90°C/W
M. Multi Layer Theta Jc:	27°C/W

IV. Die Information

A. Dimensions:	85 X 125 mils
B. Passivation:	Si_3N_4/SiO_2 (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Al/0.5%Cu with Ti/TiN Barrier
D. B ackside Metallization:	None
E. Minimum Metal Width:	3.0 microns (as drawn)
F. Minimum Metal Spacing:	3.0 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Is olation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw



V. Quality Assurance Information

A. Quality Assurance Contacts:	Don Lipps (Manager, Reliability Engineering) Bryan Preeshl (Vice President of QA)
B. Outgoing Inspection Level:	0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.
C. Observed Outgoing Defect Rate:	< 50 ppm
D. S ampling Plan:	Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = \underbrace{1}_{\text{MTTF}} = \underbrace{1.83}_{192 \times 4340 \times 208 \times 2}$ (Chi square value for MTTF upper limit) $\chi = 5.3 \times 10^{-9}$ $\lambda = 5.3 \text{ F.I.T.} (60\% \text{ confidence level @ 25°C})$

The following failure rate represents data collected from Maxim''s reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maxim-ic.com/qa/reliability/monitor. Cumulative monitor data for the B3 Process results in a FIT Rate of 0.51 @ 25C and 8.79 @ 55C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (ESD lot N1MABQ001B D/C 0216, Latch-up lot N1MACA016A D/C 0538)

The RT12 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500V per Mil-Std 883 Method 3015.7. Latch-Up testing has shown that this device withstands a current of +/-250mA.



Table 1 Reliability Evaluation Test Results

MAX3093EEUE+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
Static Life Test ((Note 1)				
	Ta = 135°C	DC Parameters	48	0	N1MACA016A, D/C 0538
	Biased	& functionality	80	0	N1MABQ001B, D/C 0216
	Time = 192 hrs.		80	0	I1MAAQ001E, D/C 0031

Note 1: Life Test Data may represent plastic DIP qualification lots.